# NSN 5961-00-442-6082

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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

# **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Internal Junction Configuration:

Pnp

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

2.0 breakdown voltage, collector-to-base, emitter open

# **Current Rating Per Characteristic:**

1.00 amperes source cutoff current

# Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

## Fiig:

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